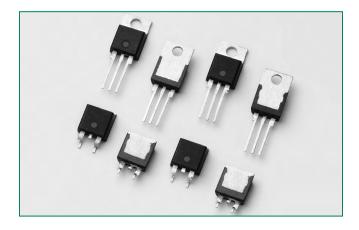


Sxx20x & Sxx25x Series





Description

Excellent unidirectional switches for phase control applications such as heating and motor speed controls.

Standard phase control SCRs are triggered with few milliamperes of current at less than 1.5V potential.

Features & Benefits

- RoHS compliant
- Glass passivated junctions
- Voltage capability up to 1000 V
- Surge capability up to 350 A

Agency Approval

Agency	Agency File Number
71	L Package: E71639

Applications

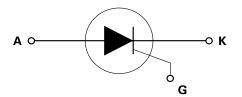
Typical applications are AC solid-state switches, industrial power tools, exercise equipment, white goods and commercial appliances.

Internally constructed isolated packages are offered for ease of heat sinking with highest isolation voltage.

Main Features

Symbol	Value	Unit
I _{T(RMS)}	20 & 25	А
V _{DRM} /V _{RRM}	400 to 1000	V
I _{GT}	30 to 35	mA

Schematic Symbol



Additional Information







Samples

Absolute Maximum Ratings — 20A SCR

Symbol	Parameter	Test Conditions		Value	Unit	
I _{T(RMS)}	RMS on-state current	T _C =	80°C	20	А	
I _{T(AV)}	Average on-state current	Sxx20x & Sxx20L	T _C = 80°C	12.8	А	
			rcle; f = 50Hz; l) = 25°C	255	^	
I _{TSM}	Peak non-repetitive surge current	single half cycle; $f = 60Hz$; T_J (initial) = 25°C		300	А	
l²t	I²t Value for fusing	t _p = 8.3 ms		374	A ² s	
di/dt	Critical rate of rise of on-state current	f = 60Hz ; T _J = 125°C		125	A/µs	
I _{GM}	Peak gate current	T _J = 125°C		3	А	
P _{G(AV)}	Average gate power dissipation	T _J = 125°C		0.6	W	
T _{stg}	Storage temperature range			-40 to 150	°C	
T _J	Operating junction temperature range			-40 to 125	°C	

Teccor® brand Thyristors 20 / 25 Amp Standard SCRs

Absolute Maximum	Ratings —	25A SCR

Symbol	Parameter	Test Conditions		Value	Unit
1	RMS on-state current		Sxx25L: T _c =75°C		А
I _{T(RMS)}	THIVIS OIT-State Current	Sxx25R/Sxx2	5N: T _c =100°C	- 25	
1	Average on-state current	Sxx25L	$T_{c} = 75^{\circ}C$	- 16	A
I _{T(AV)}	Average on-state current	Sxx25R/Sxx25N	T _C = 100°C	10	A
		single half cycle; f = 50Hz;		300	А
I _{TSM}	Peak non-repetitive surge current	T_J (initial) = 25°C			
10111		single half cycle; $f = 60Hz$; T_J (initial) = 25°C		350	
l²t	I²t Value for fusing	t _p = 8.3 ms		510	A ² s
di/dt	Critical rate of rise of on-state current	f = 60Hz ; T _J = 125°C		150	A/µs
I _{GM}	Peak gate current	T _J = 125°C		3.5	А
P _{G(AV)}	Average gate power dissipation	T _J = 125°C		0.8	W
T _{stg}	Storage temperature range			-40 to 150	°C
T _J	Operating junction temperature range			-40 to 125	°C

Electrical Characteristics (T_J = 25°C, unless otherwise specified)

				Value		
Symbol	Test Conditions			Sxx20L	Sxx25x	Unit
1	$V_{D} = 12V R_{L} = 30 \Omega$		MAX.	30	35	mA
I _{GT}	v _D = 12 v 11 _L = 30 22		MIN.	1	1	l IIIA
V _{GT}	$V_D = 12V R_L = 30 \Omega$		MAX.	1.	.5	V
		400V		450		V/µs
	$V_D = V_{DRM}$; gate open; $T_J = 100$ °C	600V		425		
		800V	MIN.	400		
dv/dt		1000V		200		
		400V		35	50	
	$V_D = V_{DRM}$; gate open; $T_J = 125$ °C	600V		325		-
		800V		300		
V _{GD}	$V_D = V_{DRM} R_L = 3.3 \text{ k}\Omega T_J = 125^{\circ}\text{C}$		MIN.	0.2		V
I _H	$I_T = 400 \text{mA} \text{ (initial)}$		MAX.	40	50	mA
t _q	(1)		MAX.	3	5	μs
t _{gt}	$I_{G} = 2 \times I_{GT}$ PW = 15 μ s $I_{T} = 40$ A		TYP.	2	2	μs

Note: xx = voltage, x = package(1) $l_T=2A$; $t_p=50\mu s$; $dv/dt=5V/\mu s$; $di/dt=-30A/\mu s$



Static Characteristics							
Symbol		Test Condition	าร		Value	Unit	
\/	20A D	evice $I_{T} = 40A$; $t_{p} = 380$)µs	MAX.	1.6	V	
V _{TM}	V_{TM} 25A Device $I_{T} = 50A$; $t_{p} = 380\mu s$				1.0	V	
		T _J = 25°C -	400 – 600V		10		
			800 – 1000V		20		
			400 – 600V		500		
I_{DRM} / I_{RRM}	V _{DRM} / V _{RRM}	$T_J = 100$ °C	800V MAX. 1000	1000	μΑ		
			1000V	-	3000		
		T __ = 125°C	400 – 600V		1000		
		1 _J = 125 C	800V		2000		

Thermal Resistances						
Symbol	Parameter		Value	Unit		
D	lunction to cook (AC)	Sxx25R / Sxx25N	1.0	°C/W		
$R_{\theta(J-C)}$	Junction to case (AC)	Sxx20L/ Sxx25L	2.4	C/VV		
		Sxx25R	40			
R _{θ(J-A)} Junction to ambien	Junction to ambient	Sxx20L / Sxx25L	50	°C/W		

Note: xx = voltage

Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature

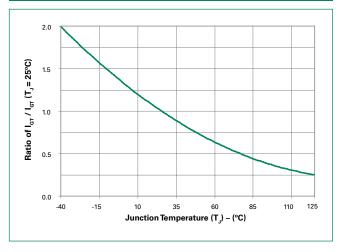


Figure 2: Normalized DC Gate Trigger Voltage vs. Junction Temperature

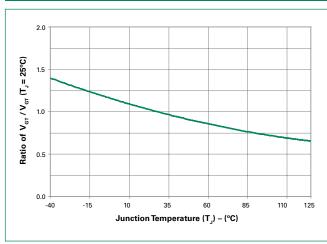




Figure 3: Normalized DC Holding Current vs. Junction Temperature

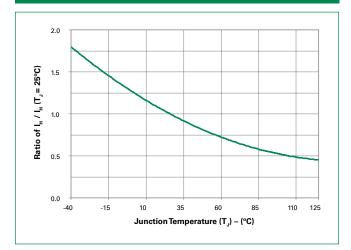


Figure 5: Power Dissipation (Typical) vs. RMS On-State Current

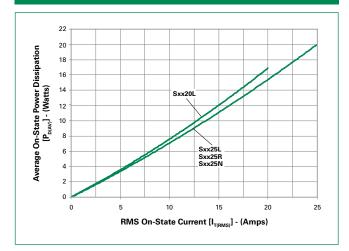


Figure 7: Maximum Allowable Case Temperature vs. Average On-State Current

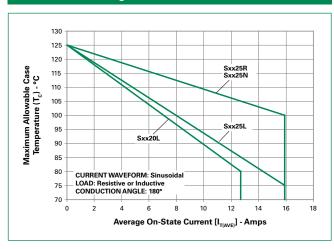


Figure 4: On-State Current vs. On-State Voltage (Typical)

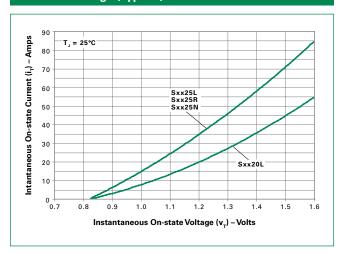


Figure 6: Maximum Allowable Case Temperature vs. RMS On-State Current

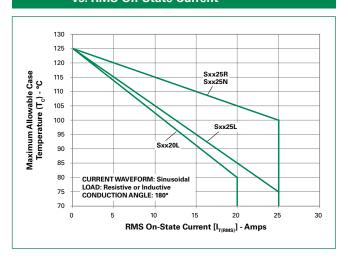


Figure 8: Maximum Allowable Ambient Temperature vs. RMS On-State Current

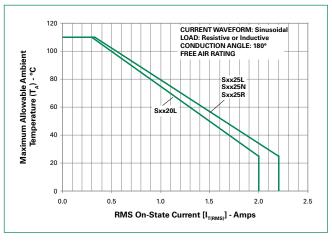
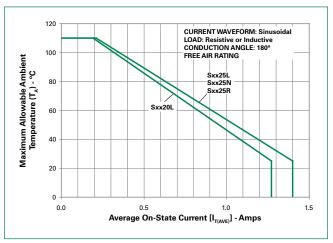




Figure 9: Maximum Allowable Ambient Temperature vs. Average On-State Current



Note: xx = voltage

Figure 10: Peak Capacitor Discharge Current

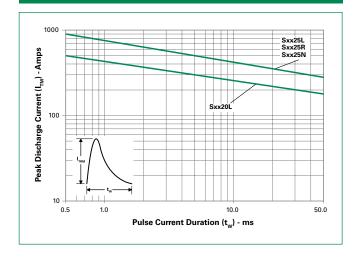


Figure 11: Peak Capacitor Discharge Current Derating

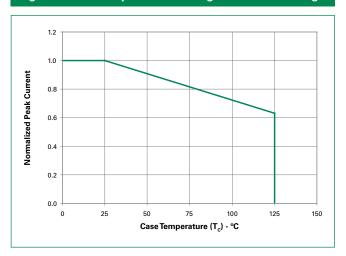
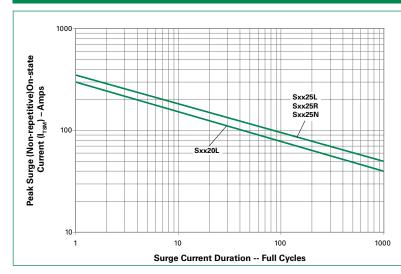


Figure 12: Surge Peak On-State Current vs. Number of Cycles



SUPPLY FREQUENCY: 60 Hz Sinusoidal

LOAD: Resistive

RMS On-State Current: [$I_{T(RMS)}$]: Maximum Rated Value at Specified Case Temperature

Notes:

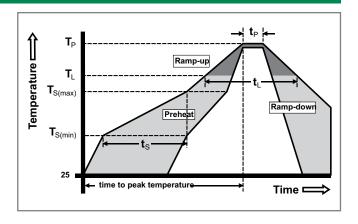
- 1. Gate control may be lost during and immediately following surge current interval.
- Overload may not be repeated until junction temperature has returned to steady-state rated value.

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Teccor® brand Thyristors 20 / 25 Amp Standard SCRs

Soldering Parameters

Reflow Condition		Pb – Free assembly
	-Temperature Min (T _{s(min)})	150°C
Pre Heat	-Temperature Max (T _{s(max)})	200°C
	-Time (min to max) (t _s)	60 – 180 secs
Average ramp up rate (Liquidus Temp) (T _L) to peak		5°C/second max
T _{S(max)} to T _L - Ramp-up Rate		5°C/second max
Reflow	-Temperature (T _L) (Liquidus)	217°C
nellow	-Temperature (t _L)	60 – 150 seconds
PeakTemp	erature (T _P)	260+ ^{0/-5} °C
Time within 5°C of actual peak Temperature (t _p)		20 - 40 seconds
Ramp-dov	vn Rate	5°C/second max
Time 25°C	to peakTemperature (T _P)	8 minutes Max.
Do not exc	ceed	280°C
	·	· ·



Physical Specifications

Terminal Finish	100% Matte Tin-plated
Body Material	UL recognized epoxy meeting flammability classification 94V-0
Lead Material	Copper Alloy

Design Considerations

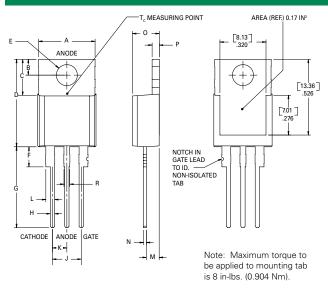
Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Environmental Specifications

Test	Specifications and Conditions
AC Blocking	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 125°C for 1008 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time
Temperature/ Humidity	EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity
High Temp Storage	MIL-STD-750, M-1031, 1008 hours; 150°C
Low-Temp Storage	1008 hours; -40°C
Resistance to Solder Heat	MIL-STD-750 Method 2031
Solderability	ANSI/J-STD-002, category 3, Test A
Lead Bend	MIL-STD-750, M-2036 Cond E

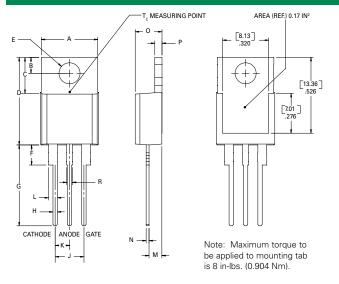


Dimensions — TO-220AB (R-Package) — Non-Isolated Mounting Tab Common with Center Lead



Dimension	Inc	hes	Millin	neters
Dimension	Min	Max	Min	Max
А	0.380	0.420	9.65	10.67
В	0.105	0.115	2.67	2.92
С	0.230	0.250	5.84	6.35
D	0.590	0.620	14.99	15.75
Е	0.142	0.147	3.61	3.73
F	0.110	0.130	2.79	3.30
G	0.540	0.575	13.72	14.61
Н	0.025	0.035	0.64	0.89
J	0.195	0.205	4.95	5.21
K	0.095	0.105	2.41	2.67
L	0.060	0.075	1.52	1.91
М	0.085	0.095	2.16	2.41
N	0.018	0.024	0.46	0.61
0	0.178	0.188	4.52	4.78
Р	0.045	0.060	1.14	1.52
R	0.038	0.048	0.97	1.22

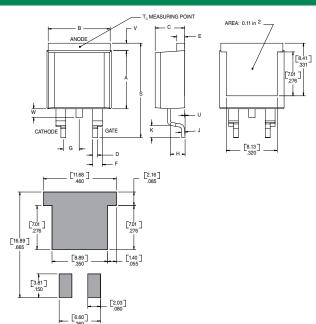
Dimensions — TO-220AB (L-Package) — Isolated Mounting Tab



Dimension	Inc	hes	Millimeters		
	Min	Max	Min	Max	
А	0.380	0.420	9.65	10.67	
В	0.105	0.115	2.67	2.92	
С	0.230	0.250	5.84	6.35	
D	0.590	0.620	14.99	15.75	
Е	0.142	0.147	3.61	3.73	
F	0.110	0.130	2.79	3.30	
G	0.540	0.575	13.72	14.61	
Н	0.025	0.035	0.64	0.89	
J	0.195	0.205	4.95	5.21	
K	0.095	0.105	2.41	2.67	
L	0.060	0.075	1.52	1.91	
М	0.085	0.095	2.16	2.41	
N	0.018	0.024	0.46	0.61	
0	0.178	0.188	4.52	4.78	
Р	0.045	0.060	1.14	1.52	
R	0.038	0.048	0.97	1.22	

Teccor® brand Thyristors 20 / 25 Amp Standard SCRs

Dimensions –TO- 263AB (N-package) — D²-Pak Surface Mount



Dimension	Inc	hes	Millimeters		
	Min	Max	Min	Max	
А	0.360	0.370	9.14	9.40	
В	0.380	0.420	9.65	10.67	
С	0.178	0.188	4.52	4.78	
D	0.025	0.035	0.64	0.89	
E	0.045	0.060	1.14	1.52	
F	0.060	0.075	1.52	1.91	
G	0.095	0.105	2.41	2.67	
Н	0.092	0.102	2.34	2.59	
J	0.018	0.024	0.46	0.61	
K	0.090	0.110	2.29	2.79	
S	0.590	0.625	14.99	15.88	
V	0.035	0.045	0.89	1.14	
U	0.002	0.010	0.05	0.25	
W	0.040	0.070	1.016	1.78	

Product Selector

Part Number -	Voltage				Coto Sonoitivity	Time	Dooleana
Part Number	Imber 400V 600V 800V 1000V Gate Sensitivity	Gate Sensitivity	Туре	Package			
Sxx20L	X	X	X	X	30mA	Standard SCR	TO-220L
Sxx25L	X	X	X	X	35mA	Standard SCR	TO-220L
Sxx25R	X	X	X	X	35mA	Standard SCR	TO-220R
Sxx25N	X	X	X	X	35mA	Standard SCR	TO-263

Note: xx = Voltage

Packing Options

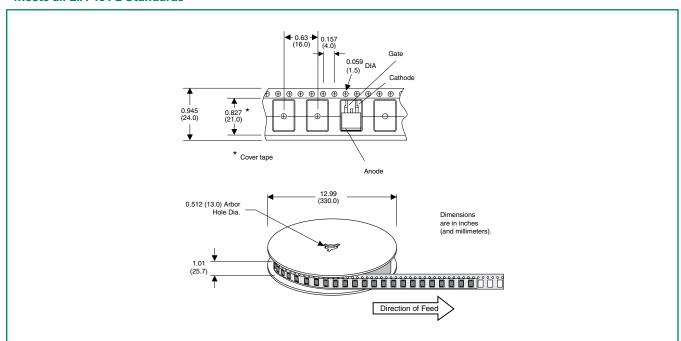
Part Number	Marking	Weight	Packing Mode	Base Quantity
Sxx20LTP	Sxx20L	2.2g	Tube	500 (50 per tube)
Sxx25LTP	Sxx25L	2.2g	Tube	500 (50 per tube)
Sxx25RTP	Sxx25R	2.2g	Tube	500 (50 per tube)
Sxx25NTP	Sxx25N	1.6g	Tube	500 (50 per tube)
Sxx25NRP	Sxx25N	1.6g	Embossed Carrier	500

Note: xx = Voltage



TO-263 Embossed Carrier Reel Pack (RP) Specifications

Meets all EIA-481-2 Standards



Part Numbering System

S 60 20 L 56 DEVICE TYPE S: SCR LEAD FORM DIMENSIONS xx: Lead Form Option VOLTAGE RATING SENSITIVITY & TYPE 40: 400V 60: 600V (blank): Sxx20L = 30mA 80: 800V K0: 1000V Sxx25x = 35mAPACKAGE TYPE CURRENT RATING L: TO-220 Isolated 20: 20A 25: 25A R: TO-220 Non-Isolated N: TO-263 (D ²-Pak)

Part Marking System

